




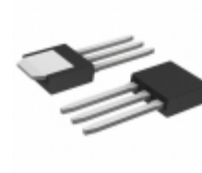





	GP1M003A050FG	
	Manufacturer Part Number:	GP1M003A050FG
	Manufacturer/Brand:	Global Power Technologies Group
	Part of Description:	MOSFET N-CH 500V 2.5A TO220F
<p>Image may be representation. See specs for product details.</p>	Datasheets:	 GP1M003A050FG.pdf
	RoHs Status:	 Lead free / RoHS Compliant
	Stock Condition:	New original, 1994 pcs Stock Available.
	Ship From:	Hong Kong
	Shipment Way:	DHL/Fedex/TNT/UPS/EMS

Specifications

Part Number	GP1M003A050FG
Manufacturer	Global Power Technologies Group
Description	MOSFET N-CH 500V 2.5A TO220F
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	1994 pcs Stock
Series	-
Technology	MOSFET (Metal Oxide)
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-220-3 Full Pack
Supplier Device Package	TO-220F
Power Dissipation (Max)	17.3W (Tc)
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	500V
Current - Continuous Drain (Id) @ 25°C	2.5A (Tc)
Rds On (Max) @ Id, Vgs	2.8 Ohm @ 1.25A, 10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	395pF @ 25V
Packaging	Tube

GP1M003A050FG is New Original in Stock, Search GP1M003A050FG Datasheets, PDF, Inventory at Y-IC.com Online, Order GP1M003A050FG Global Power Technologies Group with warrantied and confidence. RFQ GP1M003A050FG : Info@Y-IC.com

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D GP1FAV31TK0F	⊗ GP1FAV50RK0F	⊥ GP1FAV50TK0F	⊗ GP1FAV51TK0F	↔ GP1FD320TP0F
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↔ GP1S093HCZ0F	⊗ GP1S093HCZ0F	⊥ GP1S094HCZ0F	⊗ GP1S094HCZ0F	↔ GP1S094HCZ0F

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